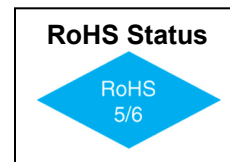


VF940
VCXO, 3.3V or 5.0V
12.62 x 20.32 mm, HCMOS/TTL



Features

- Wide pull range – up to $\pm 1,000$ ppm for some frequencies
- Fundamental crystal design
- Hermetically sealed package



Electrical Specifications

Parameter	Symbol	Condition	Min	Typ	Max	Unit	Note	
Frequency Range	F		1.54		200	MHz		
Frequency Stability	$\Delta F/F$	Vs. Operating Temperature, V_{CC}			± 25	ppm		
Operating Temperature	T		-40		+85	$^{\circ}\text{C}$		
Supply Voltage	V_{CC}		4.75 3.15	5.0 3.3	5.25 3.45	V		
Supply Current	I_{CC}	No load		20		mA	@ 20MHz	
Load		10 TTL gates or 50 pF max., AC coupled 50 Ohms termination recommended for F > 54MHz						
Duty Cycle		@ 1.4V	40	50	60	%	Note 1	
Rise & Fall Times	T_R/T_F	20% to 80%			6 3	ns	F < 54MHz F > 54MHz	
Output Levels	V_{OH}	Max load	$0.9 V_{CC}$					
	V_{OH}	Max load			$0.1 V_{CC}$			
Start-up Time	T_S			2	10	ms		
Phase Jitter		1σ			1	ps	fj > 1kHz	

Note 1: $\pm 5\%$ symmetry available, contact factory for tighter requirements.

VF940
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Electrical Specifications

Parameter	Symbol	Condition	Min	Typ	Max	Unit	Note
Modulation Bandwidth	fm	@ V _C = 2.5V	10			kHz	@ -3dB
Input Impedance		fm < 10kHz	50			kOhm	
Absolute Pull Range	APR	Overall	±50			ppm	Note 2
Deviation Slope		Monotonic, positive		±50 ±75		ppm/V	5.0V 3.3V
Linearity					±20	%	Note 3
Setability (V _C for center frequency)	V _{C0}	@ 25°C, F _{NOM}	2.00 1.25	2.50 1.65	3.00 2.05	V	Note 4 LV Option

Note 2: Up to ±1,000 ppm pull range available at some frequencies.

Note 3: ±10% and ±5% linearity available.

Note 4: 0 to 5V control voltage available for V_{CC} 3.3V. Nominal control voltage is 2.5V and setability is ±0.5V in this case.

Absolute Maximum Ratings

Parameter	Symbol	Condition	Min	Typ	Max	Unit	Note
Input Break Down Voltage	V _{CC}		-0.5		+7.0	V	
Storage Temperature	T _s		-40		+85	°C	
Control Voltage	V _C		-1		+9	V	

Environmental and Mechanical Conditions

Parameter	Condition
Mechanical Shock	MIL STD 202, Method 213, Condition E
Thermal Shock	MIL STD 883, Method 1011, Condition A
Vibration	MIL STD 883, Method 2007, Condition A
Soldering Conditions	260°C, for 10s max
Hermetic Seal	Leak rate less than 5x10 ⁻⁸ atm.cc/s of helium
Marking	Epoxy ink or laser engraved

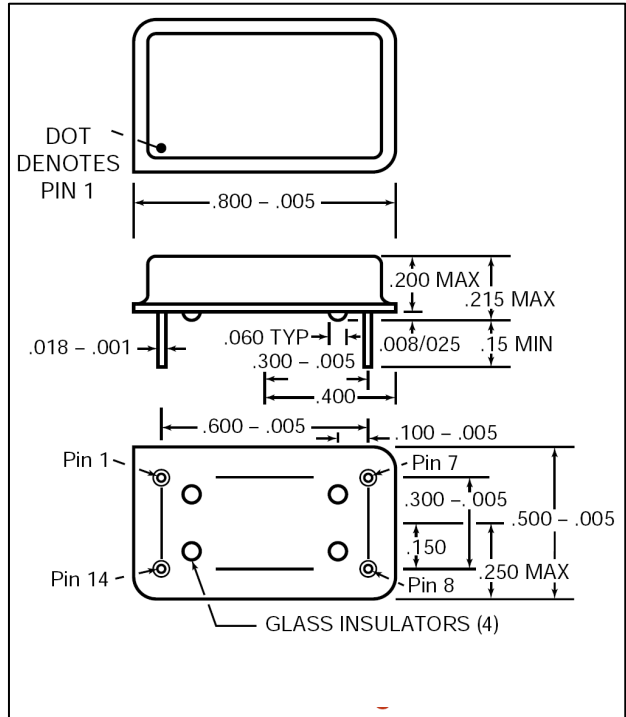
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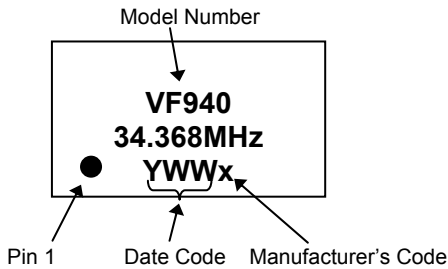
Pin Assignments

Pin #	Connection
1	V _{CONTROL}
7	Ground, Case
8	Output
14	V _{CC}

Package



Marking Specification



How to Order

